

IQID2X75D60B3

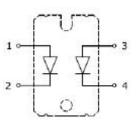
Parallel Fast Recovery, 2X75A, 600V Diodes In Isolated SOT227 Package

APPLICATIONS

- > Switch mode power supplies (SMPS) rectifiers
- Resonant applications
- Industrial drives

FEATURES

- ➢ Fast recovery
- Soft switching
- Low reverse recovery charge
- Low forward voltage drop
- Low leakage current
- Pb-free finished; RoHS compliant





Maximum Ratings (per Diode)

| Parameter | Symbol | Value | Units |
|---|------------------|-----------|-------|
| Repetitive peak reverse voltage | V _{RRM} | 600 | V |
| Continuous forward current Tc= 25°C Tc= 77°C | lF | 100 75 | |
| Surge non-repetitive forward current T _C = 25°C, t_p = 10 ms, sine halfwave | IFSM | 220 | A |
| Maximum repetitive forward current T _C = 25°C, t _p limited by T_{jmax} , D = 0.5 | I _{FRM} | 225 | |
| Soldering temperature Wave soldering, 1.6 mm (0.063 in.) from case for 10s | Ts | 260 | °C |
| Operating junction and storage temperature | Tj, Tstg | -55 +175 | °C |

Thermal and Isolation Characteristics

| Parameter | Symbol | Max. Value | Units |
|--|-------------------|------------|-------|
| Characteristics | | | |
| Thermal resistance, junction to case, per Diode | RthJC | 0.65 | |
| Thermal resistance, junction to ambient, leaded | R _{thJA} | 40 | K/W |
| Isolation voltage, RMS (measured between terminals and mounting base, 50-60 Hz, for 1-3 seconds) | Viso | 3000 | V |

Electrical Characteristics (per Diode), at T_j = 25°C, unless otherwise specified

| Parameter | Symbol | Value | | | 11 |
|--|----------------|-------|--------------|------------|------|
| | | Min. | Тур. | Max. | Unit |
| Static Characteristics | | | | | |
| Reverse leakage current VR = 600V, Tj = 25°C VR = 600V, Tj = 175°C | I _R | - | - | 40 1000 | μA |
| Forward voltage drop IF = 75A, Tj = 25°C IF = 75A, Tj = 175°C | VF | - | 1.65 1.65 | 2.0 | V |

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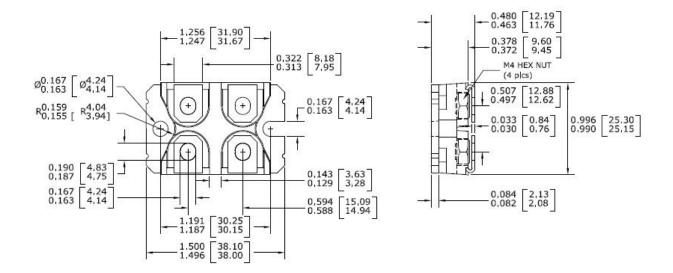
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| Parameter | Symphol | Value | | | 11 *4 |
|---|---------|-------|-------------|------|-------|
| | Symbol | Min. | Тур. | Max. | Unit |
| Dynamic Characteristics | | | | | |
| Reverse recovery time $V_R = 300V$, $I_F = 75A$, $di_F/dt = 200A/\mu s$, $T_j = 25^{\circ}C$ $V_R = 300V$, $I_F = 75A$, $di_F/dt = 200A/\mu s$, $T_j = 125^{\circ}C$ | trr | - | 264 548 | - | ns |
| Peak reverse current V _R = 300V, I _F = 75A, di _F /dt = 200A/µs, T _J = 25°C V _R = 300V, I _F = 75A, di _F /dt = 200A/µs, T _J = 125°C | Irm | - | 8.3 12.9 | | А |
| Reverse recovery charge $V_R = 300V$, $I_F = 75A$, $di_F/dt = 200A/\mu s$, $T_j = 25 \circ C$ $V_R = 300V$, $I_F = 75A$, $di_F/dt = 200A/\mu s$, $T_j = 125 \circ C$ | Qrr | - | 908 2941 | - | nC |

Electrical Characteristics (per Diode), at T_j = 25°C, unless otherwise specified

Package Outline Drawing



Disclaimer

These specifications may not be considered as a guarantee of components characteristics. Components have to be tested depending on intended application as adjustments may be necessary. The use of **iQXPRZ Power Inc.** components in life support appliances and systems are subject to written approval of **iQXPRZ Power Inc.**

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